Transistors 2SC184

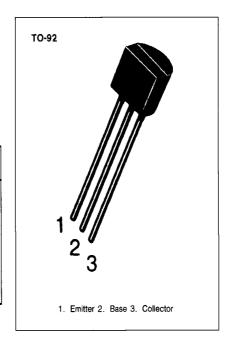


AM FREQUENCY CONVERTER IF AMPLIFIER

- Current Gain Bandwidth Product f_T = 100MHz (Typ)
- Complement to KSA542

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Collector-Base Voltage	V _{CBO}	30	V	
Collector-Emitter Voltage	V _{CEO}	25	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Collector Current	l _G	50	mA	
Collector Dissipation	Pc	250	mW	
Junction Temperature	Ti	150	°C	
Storage Temperature	Tstq	~55~150	°C	



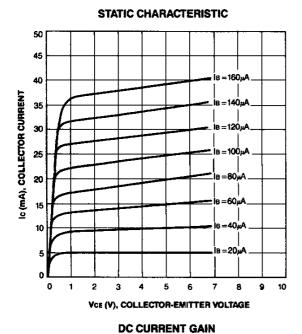
ELECTRICAL CHARACTERISTICS (Ta=25°C)

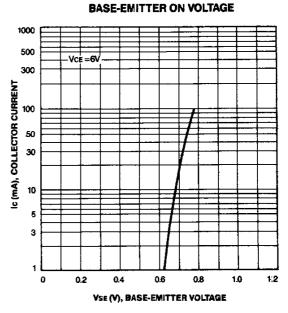
Characteristic	Symbol Test Conditions		Min	Тур	Max	Unit
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =100μA, I _E =0	30			٧
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =10mA, I _B =0	25			٧
Emitter-Base Breakdown Voltage	BVEBO	$I_E = 10 \mu A, I_C = 0$	5]	V
Collector Cut-off Current	Icao	V _{CB} = 25V, I _E = 0			0.1	μA
Emitter Cut-off Current	I _{EBO}	V _{FB} =5V, I _C =0			0.1	μA
DC Current Gain	hee	V _{CE} =6V, I _C =1mA	40		1000	'
Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _C =10mA, I _B =1mA		0.1	0.2	V
Current Gain-Bandwidth Product	fr	V _{CE} =6V, I _C =1mA		100		MHz
Output Capacitance	Cob	V _{CB} =6V, I _E =0 f=1MHz		2.6	4.4	pF

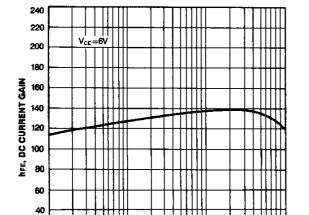
hFE CLASSIFICATION

Classification	R	0	Y	G	L	V
h _{FE}	40-80	70-140	120-240	200-400	350-700	600-1000

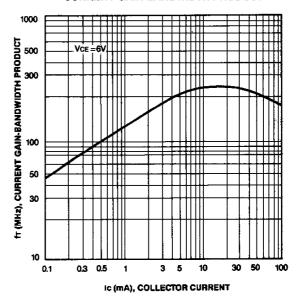














3 5

10

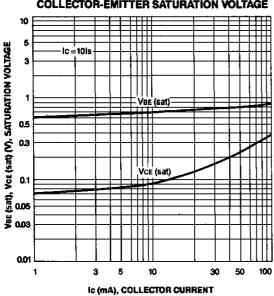
30 50

100

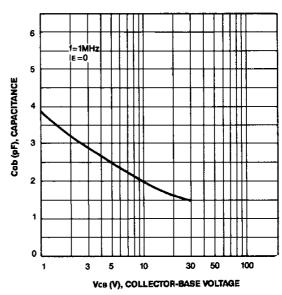
20 0

0.1

0.3 0.5



COLLECTOR OUTPUT CAPACITANCE



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